

UTC UNISONIC TECHNOLOGIES CO., LTD

BAT54CW DIODE

SCHOTTKY BARRIER (DUAL) **DIODES**

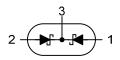
DESCRIPTION

Planar Schottky barrier diodes are encapsulated in the SOT-323 small plastic SMD package. Single diodes and dual diodes with different pin configuration are available.

FEATURES

- * Low forward voltage
- * Guard ring protected
- * Small plastic SMD package

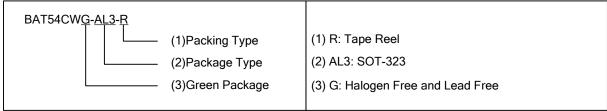




ORDERING INFORMATION

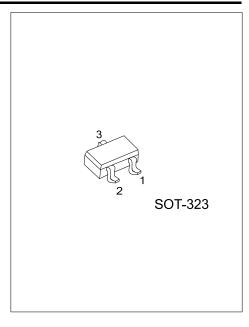
Ordering Number	Daakana	Pin Assignment			Daaliaa	
Halogen Free	Package	1	2	3	Packing	
BAT54CWG-AL3-R	SOT-323	A1	A2	K2K1	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



MARKING





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■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT		
PER DIODE	PER DIODE				
Continuous Reverse Voltage	V_R	30	V		
Continuous Forward Current	l _F	200	mA		
Repetitive Peak Forward Current (t _P <1s, δ≤0.5)	I _{FRM}	300	mA		
Non-repetitive Peak Forward Current (t _P <10ms)	I _{FSM}	600	mA		
Junction Temperature	T_J	+125	°C		
Storage Temperature	T _{STG}	-60 ~ +150	°C		
PER DEVICE					
Power Dissipation (T _A ≤25°C)	P_{D}	230	mW		

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	625	°C/W

■ ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage (See Fig.1)	·	$I_F = 0.1 \text{mA}$			240	mV
		I _F = 1mA			320	mV
		I _F = 10mA			400	mV
		I _F = 30mA			500	mV
		I _F = 100mA			800	mV
Reverse Current (See Fig.2)	I_{R}	V _R = 25V			2	μΑ
Reverse Recovery Time (see Fig.4) t _{rr}		When switched from I _F =10mA				
		to $I_R = 10$ mA, $R_L = 100\Omega$			5	ns
		measured at I _R = 1mA				
Diode Capacitance (see Fig.3)	C_D	$f = 1 MHz, V_R = 1V;$			10	pF

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■ TYPICAL CHARACTERISTICS

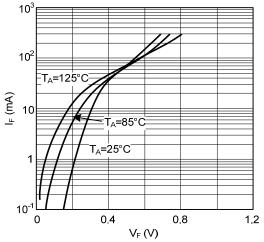


Fig.1 Forward current as a function of forward voltage; typical values.

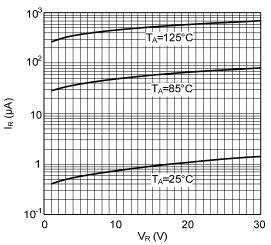


Fig.2 Reverse current as a function of reverse voltage; typical values.

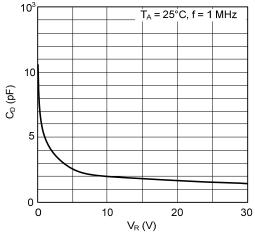


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

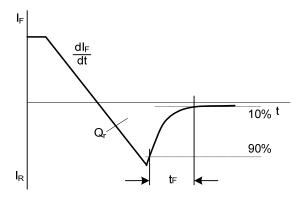


Fig.4 Reverse recovery definitions

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